## **ELECTRONICS**

1.	In a bridge-type full-wave rectifier, if $V_m$ is the peak voltage across the secondary of the transformer, the maximum voltage coming across each reverse-biased diode is:				
	(a)	$V_m$			
	(b)	2 V <sub>m</sub>			
500	(e)	$\frac{1}{2} V_m$			
	(d)	$V_m / \sqrt{2}$			
2.	Whi	Which of the following is a unipolar device?			
	(a)	P-N junction diode			
	<b>(b)</b>	Zener diode			
	(c)	Tunnel diode			
	(d)	Schottky diode			
3.	Lowest output resistance is obtained in :				
	(a)	CB			
	(b)	CE			
	(c)	CC			
	(d)	both (a) and (b)			
4.	In t	he case of BJT amplifier, bias stability is achieved by:			
	(a)	keeping the base current constant			
	(b)	keeping $I_{\rm C}$ and $V_{\rm CE}$ constant irrespective of the undesired changes in base current			
	(c)	keeping the temperature constant			
	(d)	keeping the temperature and base current constant			
5.	JFE	T has main drawback of :			
	(a)	having low input impedance			
	<b>(b)</b>	having high output impedance			
	(c)	being noisy			
	(d)	having small gain-bandwidth product			
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6.	The most popular form of IC package is:			
	(a)	TO-5		
12	(b)	DIL		
	(c)	Flat Pack		
	(d)	All of the above		
7.	Апе	twork is said to be non-linear if it does not satisfy:		
	(a)	homogenity condition		
	(b)	superposition condition		
	(c)	both (a) and (b)		
	(d)	associative condition		
8.	The a	superposition theorem is applicable to :		
	(a)	linear, non-linear and time variant responses		
	(b)	linear and non-linear resistors only		
	(c)	linear responses only		
	(d)	none of the above		
9.	Selec	tivities of different resonance circuits are compared in terms of their :		
	(a)	impedances		
	(b)	reactances		
	(c)	frequencies		
	(d)	bandwidths		
10.	The	dual of a loop is:		
	(a)	twig		
	<b>(b)</b>	node		
	(c)	mesh		
	(d)	tree		
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11.	A square wave with a period of 10 $\mu s$ drives a T flip-flop. The period of the output signal will be :			
	(a)	100 με		
	(b)	20 μs		
	(c)	10 μs		
	(d)	5 μs		
12.	While is the fastest unsaturated logic gate has the excellent noise immunity.			
	(a)	ECL, TTL		
	(b)	TTL, ECL		
	(c)	ECL, HTL		
	(d)	RTL, DTL		
13.	The ASCII is a 7-bit code for :			
	(a)	letters		
	(b)	numbers		
	(c)	other symbols		
	(d)	all of the above		
14.	Odd	parity of wood can be conveniently tested by :		
	(a)	XOR gate		
	<b>(P)</b>	OR gate		
	(c)	XNOR gate		
	(d)	NAND		
15.	A multiplexer is known as :			
	(a)	multivibrator		
	(b)	data selector		
	(c)	decoder		
	(d)	seven segment display		
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16.		which of the following flip-flop the output is clearly defined for all iderations of two inputs?
	(a)	D
	(b)	RS .
	(c)	JK
	<b>(d)</b>	T
17.	A co	mplete microcomputer system consists of :
	(a)	microprocessor
	<b>(b)</b>	memory
	(c)	add-ons
	<b>(d)</b>	all of the above
18.	The	most common addressing techniques employed by a CPU is :
	(a)	immediate
	<b>(b)</b>	direct
	(c)	indirect
	(d)	all of the above
19.	Whic	ch of the following is the user programmed semiconductor memory?
	(a)	SRAM
	(b)	DRAM
	(c)	EPROM
	(d)	All of the above
20.	For	a memory system, the cycle time is :
	(a)	same as the access time
	<b>(b)</b>	longer than the access time
	(c)	shorter than the access time
	(d)	none of the above
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21.	In C programming language, which of the following type of operators enjoys highest precedence:			
	(a)	relational operators		
	(b)	equality operator		
	(c)	logical operators		
	(d)	arithmetic operators		
22.	The single character input/output functions are :			
	(a)	scanf() and printf()		
	(b)	getchar() and printf()	12	
	(c)	scanf() and putchar()		
	(d)	getchar() and putchar()		
23.	The two statements that can be used to change the flow of control are :			
	(a)	if and switch		
	<b>(b)</b>	if and while		
	(c)	switch and do-while		
	(d)	break and continue		
24.	The comma operator (,) is primarily used in conjunction with :			
	(a)	for statement		
	<b>(b)</b>	if-else statement		
	(c)	do-while statement	12	
	<b>(d)</b>	all of the above		
25.	Arrays that do not have their dimensions explicitly specified are called :			
	(a)	unsized arrays		
	(b)	undimensional arrays		
	(c)	initialized arrays		
	(d)	no size of arrays		
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(c) (d) In li	Linked list with multiple pointers  None of the above  nked lists with multiple pointers:
(d)	None of the above
	565667 St. M. 7020
300000	Circular linked list
5000000	Linear linked list
	h of the following is not a linked data structure?
(d)	all have the same type
(c)	are grouped neat to each other in memory
14.55	must be structures
	all occupy the same space in memory
	ion consists of a number of elements that :
30	union
(c)	structure
<b>(b)</b>	typedef
(a)	pointer
to ex	isting data types is:
The	feature that allows you to define new data types that are equivalent
(d)	% and &
(c)	& and &&
<b>(b)</b>	* and &&
(a)	* and &
	(b) (c) (d) The : to ex (a) (b) (c) (d) A un (a) (b) (c) (d) Whice (a) (b)

C contains two special pointer operators :

26.

31,		th of the following parameters is used for distinguishing between a small		
		al and a large signal amplifier ?		
	(a)	Voltage gain		
	(b)	Frequency response		
	(c)	Harmonic distortion		
	( <b>d</b> )	Input/output impedances		
32.	Class	AB operation is often used in power amplifiers in order to :		
	(a)	get maximum efficiency		
	(b)	remove even harmonics		
	(c)	over come crossover distortion		
	(d)	reduce collector dissipation		
33.	A th	A thyristor is a semiconductor switch which is :		
	(a)	unilateral and astable		
	<b>(b)</b>	bilateral and astable		
	(c)	unilateral and bistable		
	(d)	bilateral and bistable		
34.	The	crystal oscillator frequency is very stable due to :		
	(a)	rigidity of crystal		
	<b>(b)</b>	size of crystal		
	(c)	structure of crystal		
	(d)	high Q of the crystal		
35.	The requirement of an oscillator using positive feedback amplifier as an oscillator, is that:			
	(a)	there must be positive feedback		
	<b>(b)</b>	initially the value of loop gain AB must be greater than unity		
	(c)	after the desired level is reached the loop gain AB must decrease to unity		
	(d)	all of the above		

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because of its:  (a) input voltage dependent linear transfer characteristic  (b) high voltage gain  (c) high input resistance  (d) high CMRR  38. The type of multivibrator used for generation of clock pulses is:  (a) monostable multivibrator  (b) astable multivibrator  (c) bistable multivibrator  (d) none of the above  39. The material used for the construction of LED is:  (a) Si  (b) Ge  (c) GaAsP  (d) None of the above		(a)	sine wave
(d) trapezoidal  37. Most of the linear ICs are based on the two transistor differential amplifies because of its:  (a) input voltage dependent linear transfer characteristic  (b) high voltage gain  (c) high input resistance  (d) high CMRR  38. The type of multivibrator used for generation of clock pulses is:  (a) monostable multivibrator  (b) astable multivibrator  (c) bistable multivibrator  (d) none of the above  39. The material used for the construction of LED is:  (a) Si  (b) Ge  (c) GaAsP  (d) None of the above  40. Which of the following is not classified as a photoconductive device?  (a) a photovoltaic cell  (b) a PIN photodiode  (c) a phototransistor  (d) a light dependent resistor		<b>(b)</b>	square wave
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(c) a phototransistor (d) a light dependent resistor		(a)	a photovoltaic cell
(d) a light dependent resistor		(b)	a PIN photodiode
<u></u>		(e)	a phototransistor
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	Elect	ronics	8

36. UJT when used for triggering an SCR has waveform :

41.	Electronic voltmeter provides more accurate readings in high resistance circuits				
	as compared to a non-electronic voltmeter because of :				
	(a) high V/ohm ratings	*1			

high ohm/V ratings (b)

low meter resistance (c)

high resolution (d)

In a CRT the length l of the magnetic field in the initial direction of the 42. electron beam when compared with the radius of curvature of that beam is:

very large (a)

very small (b)

(c) equal

(d) negligibly small

The Miller sweep circuit normally used in a CRO is basically : 43.

voltage to current converter circuit (a)

a current to voltage converter circuit (b)

an integrator circuit (c)

a differentiator (d)

The disadvantage of Maxwell's bridge is that : 44.

> inductance measurement is frequency dependent (a)

it cannot be used to measure inductance for large values of Q (b)

both inductance and Q cannot be measured (c)

resistance of the inductor measurement is frequency dependent

What type of bridge is recommended for measuring resistances less than 45. 1 ohm ?

(a) Wheatstone bridge

Schering bridge (b)

Maxwell bridge (c)

Kelvin bridge (d)

46.	A vol	tmeter has 100 divisions on 0-100 V range. One-tenth of each division be read with certainty. The resolution of the meter is :
	(a)	0.1 V
	(b)	0.01 V
	(c)	1.0 V
	(d)	1.01 V
47.	The	resistance of a strain gauge should be high:
	(a)	to increase sensitivity
	<b>(b)</b>	to reduce hysteresis effects
	(c)	to swamp out the effects of variations of resistance in other parts of the bridge
	(d)	none of the above
48.	Piez	o electric transducers are :
	(a)	active transducers
	(b)	passive transducers
	(c)	secondary transducers
	(d)	none of the above
49.	The	resolution of a digital ammeter with 3-digit display is:
	(a)	1/2
10	(b)	1/3
	(c)	1/8
	(d)	1/4
50.	A s	et of independent current measurements were taken and recorded as follows 8 A, 12.2 A, 12.5 A, 13.1 A, 12.9 A and 12.4 A. The standard deviation
	is	
100	(a)	0.283 A
	(b)	0.300 A

(c) (d) 0.399 A

0.414 A

- 51. In a 100% amplitude modulated signal, if the total transmitted power is P, then carrier power will be:
  - (a)  $\frac{2}{3}$  F
  - (b)  $\frac{1}{2}$  F
  - (c)  $\frac{1}{3}$  P
  - (d)  $\frac{1}{4}$  F
- 52. In a narrow band FM system, the highest modulating frequency is  $f_m$ . The bandwidth of the system will be:
  - (a)  $6 f_m$
  - (b)  $f_m$
  - (c)  $2 f_m$
  - (d)  $10 f_m$
- 53. In TV transmission, picture signal is amplitude modulated and sound signal is frequency modulated. This is done because:
  - (a) it is not possible to frequency modulate the picture signal
  - (b) bandwidth requirement is minimised
  - (c) sound signal is more susceptible to noise than picture signal
  - (d) synchronisation of picture frames becomes easier
- 54. The most common detector used in an AM radio broadcast receiver is :
  - (a) envelope detector
  - (b) coherent detector
  - (c) discriminator
  - (d) ratio detector
- 55. The main advantage of PCM system is :
  - (a) lower bandwidth
  - (b) lower power
  - (c) lower noise
  - (d) none of the above

56.	Pulse	communication system that is inherently highly immune to noise is:			
	(a)	PAM			
	(b)	PWM			
	(c)	PPM			
100	(d)	PCM ·			
57.	Which of the following antenna gives circular polarization?				
50	(a)	Yagi-uda			
	(b)	Parabolic			
	(c)	Dipole			
	(d)	Helical			
58.	The ground wave eventually disappears as one moves from transmitter because				
	of :				
	(a)	surface attenuation			
	(p)	diffraction			
	(c)	loss of line of sight			
	(d)	tilting			
59.	Whic	h of the following statements is not valid for FM systems?			
	(a)	It needs less bandwidth			
	(p)	It offers better S/N ratio			
	(c)	It requires less modulating power			
	(d)	All of the above			
60.	In a	TV which of the following stages has AGC bias?			
	(a)	Mixer			
	(b)	Local oscillator			
E s	(c)	RF amplifier			
	(d)	AFT discriminator			
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